

CMOS Digital Integrated Circuits Silicon Monolithic

TC7WB66CFK,TC7WB66CL8X TC7WB67CFK,TC7WB67CL8X

1. Functional Description

· Dual SPST Bus Switch

2. General

The TC7WB66CFK/L8X and TC7WB67CFK/L8X are low ON-resistance, high-speed CMOS 2-bit bus switches. These bus switches allow connections or disconnections to be made with minimal propagation delay while maintaining Low power dissipation which is the feature of CMOS.

TC7WB66CFK/L8X requires the output enable (OE) input to be set low to place the output into the high impedance state, whereas the TC7WB67CFK/L8X requires the output enable (\overline{OE}) input to be set high to place the output into the high impedance.

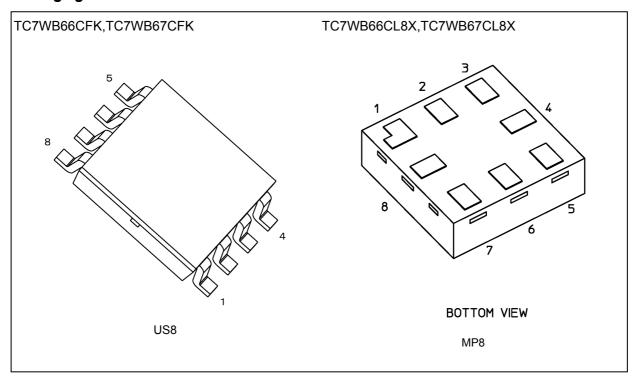
These Bus switches consist of P-MOS and N-MOS structure, meaning these devices are suitable for analog signal transmission.

All inputs are equipped with protector circuits to protect the device from static discharge.

3. Features

- (1) Operating voltage: $V_{CC} = 1.65$ to 5.5 V
- (2) ON capacitance: $C_{I/O} = 10$ pF Switch On (typ.) $@V_{CC} = 5.0$ V
- (3) ON resistance: $R_{ON} = 4 \Omega$ (typ.) @ $V_{CC} = 4.5 \text{ V}$, $V_{IS} = 0 \text{ V}$
- (4) ESD performance: Machine model ≥ ±200 V, Human body model ≥ ±2000 V
- (5) Package: US8, MP8

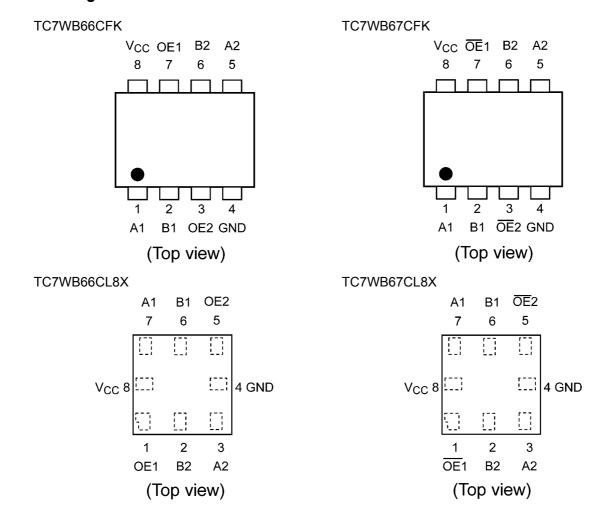
4. Packaging



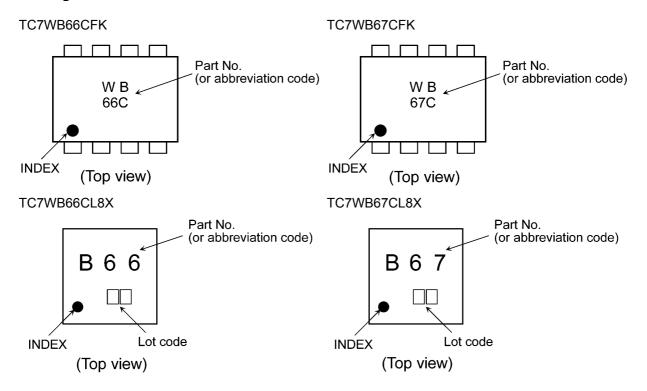
Start of commercial production



5. Pin Assignment



6. Marking

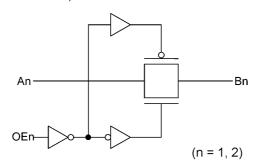


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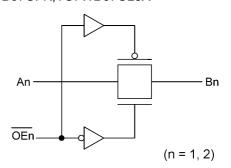


7. Block Diagram

TC7WB66CFK,TC7WB66CL8X



TC7WB67CFK,TC7WB67CL8X



8. Principle of Operation

8.1. Truth Table

Inputs OE (TC7WB66CFK/L8X)	Inputs OE (TC7WB67CFK/L8X)	Function
Н	L	A port = B port
L	Н	Disconnect

9. Absolute Maximum Ratings (Note)

Characteristics	Part Number	Symbol	Note	Rating	Unit
Supply voltage		V _{CC}		-0.5 to 7.0	V
Input voltage (OE, OE)		V _{IN}		-0.5 to 7.0	
Switch I/O voltage		Vs		-0.5 to V _{CC} +0.5	
Clamp diode current		I _{IK}		-50	mA
Switch I/O current		I _S		50	
Power dissipation	TC7WB66CFK,TC7WB67CFK	P _D		200	mW
	TC7WB66CL8X,TC7WB67CL8X]	(Note 1)	300	
V _{CC} /ground current		I _{CC} /I _{GND}		±100	mA
Storage temperature		T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on an FR4 board

10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		1.65 to 5.5	V
Input voltage (OE, OE)	V _{IN}		0 to 5.5	
Switch I/O voltage	V _S		0 to V _{CC}	
Operating temperature	T _{opr}		-40 to 85	°C
Input rise time	dt/dv		0 to 10	ns/V
Input fall time	dt/dv	·	0 to 10	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused control inputs must be tied to either V_{CC} or GND.



11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage		V _{IH}		_	1.65 to 1.95	$0.8 \times V_{CC}$		_	V
(OE, OE)					2.3 to 5.5	$0.7 \times V_{CC}$		_	
Low-level input voltage		V _{IL}		_	1.65 to 1.95	_	_	$0.2 \times V_{CC}$	
(OE, \overline{OE})					2.3 to 5.5	_	_	$0.3 \times V_{CC}$	
Input leakage current (OE, OE)		I _{IN}		V _{IN} = 0 to 5.5 V	1.65 to 5.5		l	±1.0	μА
Switch OFF-state leakage current	TC7WB66- CFK, TC7WB66- CL8X	I _{SZ}		A, B = 0 to V_{CC} , OE = GND	1.65 to 5.5		ı	±10	
	TC7WB67- CFK, TC7WB67- CL8X			$A, B = 0 \text{ to } V_{CC},$ $\overline{OE} = V_{CC}$	1.65 to 5.5			±10	
ON-resistance		R _{ON}	(Note 1), (Note 2)		4.5	_	4	7	Ω
				V _{IS} = 2.4 V, I _{IS} = 30 mA	4.5	_	5	12	
				V _{IS} = 4.5 V, I _{IS} = 30 mA	4.5	_	6	10	
				V _{IS} = 0 V, I _{IS} = 24 mA	3.0	_	5	9	
				V _{IS} = 3.0 V, I _{IS} = 24 mA	3.0	_	7	14	
				$V_{IS} = 0 V$, $I_{IS} = 8 \text{ mA}$	2.3		6	12	
				$V_{IS} = 2.3 \text{ V},$ $I_{IS} = 8 \text{ mA}$	2.3	_	9	18	
				V _{IS} = 0 V, I _{IS} = 4 mA	1.65	_	8	20	
				V _{IS} = 1.65 V, I _{IS} = 4 mA	1.65	_	15	30	
Quiescent supply current		I _{CC}		$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$ A	5.5	_	_	10	μА
		Δl _{CC}		V _{IN} = V _{CC} - 0.6 V	5.5	_		50	

Note 1: All typical values are at $T_a = 25$ °C.

11.2. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Max	Unit	
3-state output enable time	t _{PZL} /t _{PZH}			5.0 ± 0.5	_	4	ns	
				Table 11.2.1	3.3 ± 0.3	_	6	
					2.5 ± 0.2		9	
				1.8 ± 0.15		18		
3-state output disable time	t _{PLZ} /t _{PHZ}		See Fig. 11.2.1, 11.2.2,	5.0 ± 0.5	_	4.5		
	Table 11.2.1	3.3 ± 0.3		7				
			2.5 ± 0.2		0			
		1.8 ± 0.15		18				

Note 2: Measured by the voltage drop between A and B pins at the indicated current through the switch. On-resistance is determined by the lower of the voltages on the two (A or B) pins.



11.3. Capacitive Characteristics (Note) (Unless otherwise specified, Ta = 25 °C)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance (OE, OE)		C _{IN}		V _{IN} = 0 V	5.0	4	pF
Switch terminal OFF- capacitance	TC7WB66CFK, TC7WB66CL8X	C _{I/O}		OE = GND, $V_{I/O} = 0 V$	5.0	5	
	TC7WB67CFK, TC7WB67CL8X			$\overline{OE} = V_{CC}, V_{I/O} = 0 V$	5.0	5	
Switch terminal ON- capacitance	TC7WB66CFK, TC7WB66CL8X	C _{I/O}		$OE = V_{CC}, V_{I/O} = 0 V$	5.0	10	
	TC7WB67CFK, TC7WB67CL8X			OE = GND, V _{I/O} = 0 V	5.0	10	

Note: Parameter guaranteed by design.

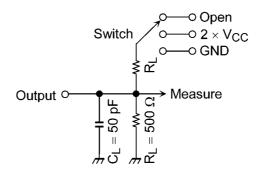


Fig. 11.2.1 AC Test Circuit

Table 11.2.1 Parameter for AC Test Circuit

Parameter	Switch
t _{PLZ} , t _{PZL}	2 × V _{CC}
t _{PHZ} , t _{PZH}	GND

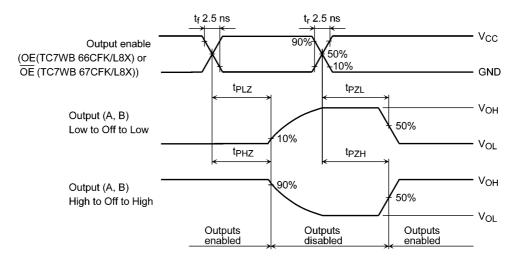


Fig. 11.2.2 AC Waveform t_{PLZ}, t_{PHZ}, t_{PZL}, t_{PZH}

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12. Rise and Fall Time (t_r/t_f)

The t_{r(out)} and t_{f(out)} values of the output signals are affected by the CR time constant of the input, which consists of the switch terminal capacitance (C_{LO}) and the on-resistance (R_{ON}) of the input.

In practice, the $t_{r(out)}$ and $t_{f(out)}$ values are also affected by the circuit's capacitance and resistance components other than the capacitance of TC7WB66CFK/L8X, TC7WB67CFK/L8X

The $t_r/t_{f(out)}$ values can be approximated as follows.

(Figure 12.1, Table 12.1 shows the test circuit.)

$$t_{r}/t_{f(out)} \; (approx) = - \left(C_{I/O} + C_{L} \right) \; \cdot \; \left(R_{DRIVE} + R_{ON} \right) \; \cdot \; ln \; \left(\left(\left(V_{OH} - V_{OL} \right) - V_{M} \right) / \left(V_{OH} - V_{OL} \right) \right)$$

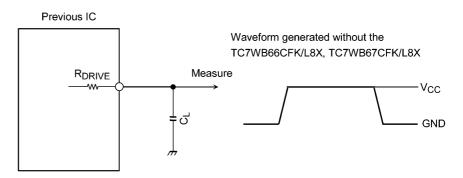
Where, $R_{\mbox{\scriptsize DRIVE}}$ is the output impedance of the previous-stage circuit.

Calculation example:

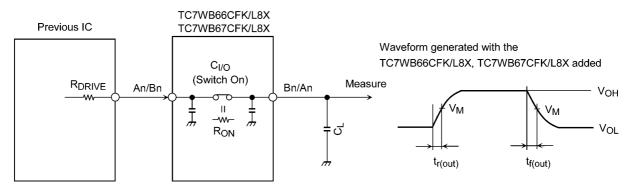
$$t_{r(out)}$$
 (approx) = $-(10 + 15)$ E -12 $+(120 + 4)$ $+\ln(((4.5 - 0) - 2.25) / (4.5 - 0)) = ≈ 2.1 ns$

Calculation conditions:

 $V_{CC} = 4.5 \text{ V}, C_L = 15 \text{ pF}, R_{DRIVE} = 120 \Omega$ (output impedance of the previous IC), $V_M = 2.25 \text{ V}$ ($V_{CC}/2$) Output of the previous IC = digital (i.e., high-level voltage = V_{CC}, low-level voltage = GND)



R_{DRIVE} = output impedance of the previous IC



RDRIVE = output impedance of the previous IC

Fig. 12.1 **Calculation Circuit**

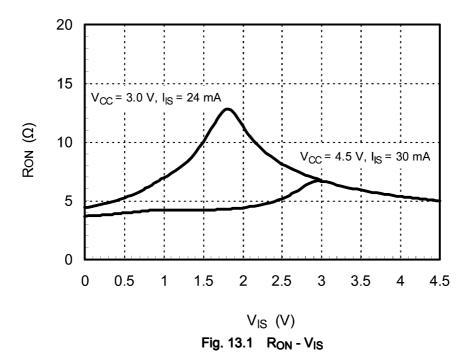
Table 12.1 Calculation Circuit

Characteristics	V_{CC} = 5.0 ± 0.5 V	V_{CC} = 3.3 \pm 0.3 V	V_{CC} = 2.5 \pm 0.2 V	V_{CC} = 1.8 \pm 0.15 V
V_{M}	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2

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13. Characteristics Curves (Note)

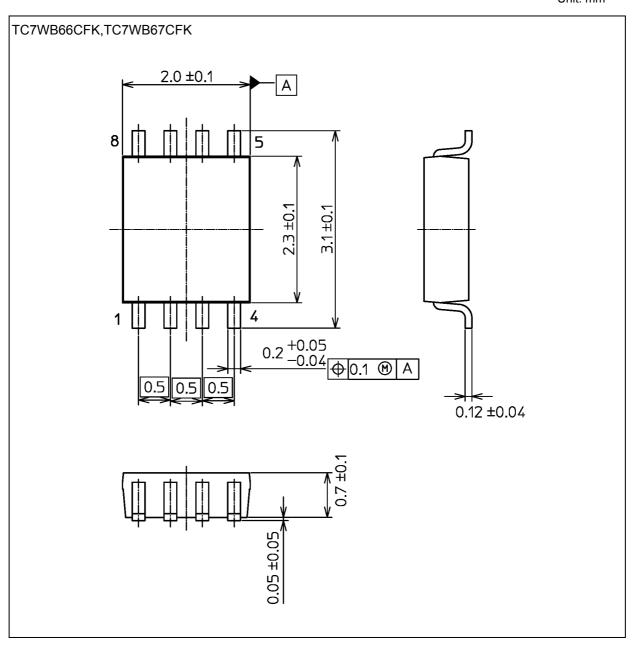


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



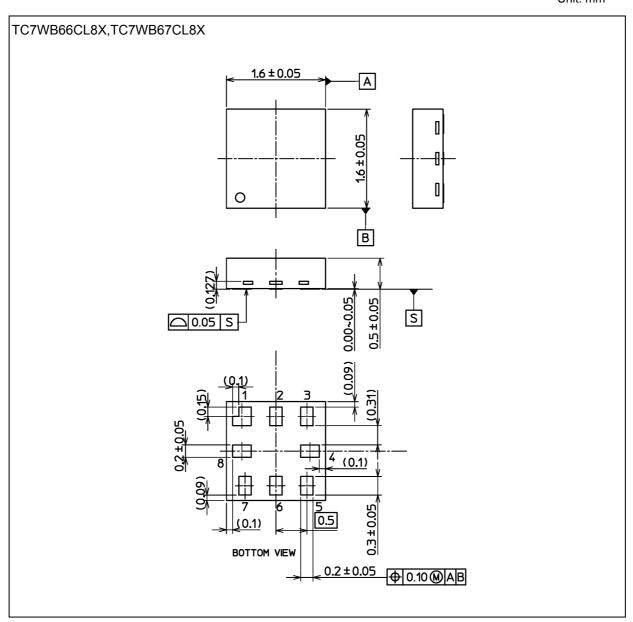
Weight: 0.01 g (typ.)

	Package Name(s)	
Nickname: US8		



Package Dimensions

Unit: mm



Weight: 0.0039 g (typ.)

	Package Name(s)	
Nickname: MP8		

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